

HIGH-STABILITY HIGH-FREQUENCY OSCILLATOR

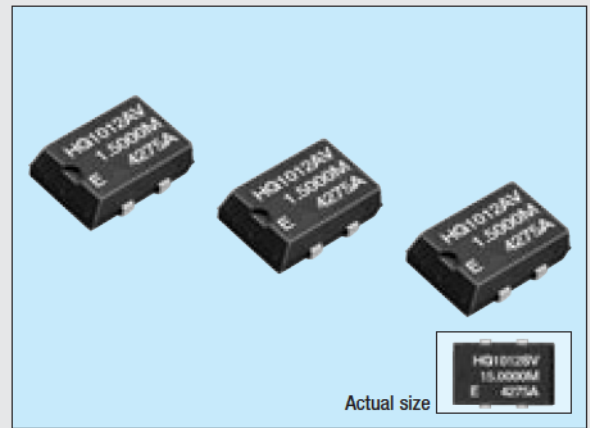
# HG-1012JA / 2012JA

Product number (please refer to page 3)

**Q3511JA0XXXXX00**

**Q3512JA0XXXXX00**

- Cylindrical AT crystal unit built-in, thus assuring high reliability.
- Excellent heat resistance.
- Low current consumption.
- Available for lead (Pb)-free soldering.
- Available for lead (Pb)-free terminal.

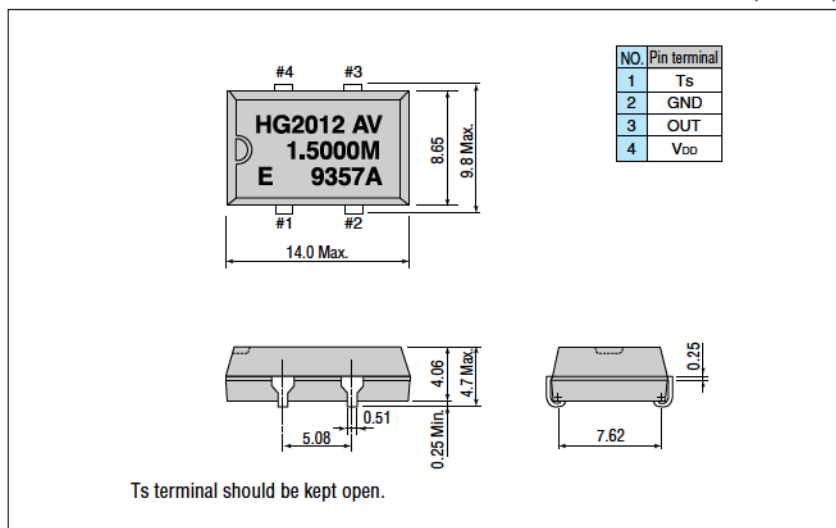


## Specifications (characteristics)

Item	Symbol	Specifications		Remarks	
		HG-1012JA	HG-2012JA		
Output frequency range	fo	1.5000 MHz to 28.63636 MHz		VDD = 4.75 V to 5.25 V	
Power source voltage	Max. supply voltage	VDD-GND	-0.5 V to +7.0 V		
	Operating voltage	VDD	5.0 V ±0.25 V		
Temperature range	Storage temperature	TSTG	-55 °C to +125 °C		Stored as bare product after unpacking
	Operating temperature	TOPR	-40 °C to +85 °C		
Frequency stability	Δf/fo	AV: ±20 x 10 <sup>-6</sup> , BV: ±25 x 10 <sup>-6</sup>		Ta = -20 °C to +70 °C	
		SV: ±15 x 10 <sup>-6</sup> , AV: ±20 x 10 <sup>-6</sup>		Ta = -40 °C to +85 °C	
Current consumption	Iop	10 mA Max.		No load condition	
Duty	tw/ t	40 % to 60 %		1/2 VDD level	
High output voltage	VOH	VDD -0.4 V Min.		IOH = -0.8 mA	
Low output voltage	VOL	0.4 V Max.		IOL = 3.2 mA	
Output load condition	CL	15 pF			
Output rise time	tr	8 ns Max.		20 % → 80 % VDD level	
Output fall time	tf	8 ns Max.		80 % → 20 % VDD level	
Oscillation start up time	tosc	4 ms Max.		Time at 4.75 V to be 0 s	
Aging	fa	±5 x 10 <sup>-6</sup> / year Max.	±2 x 10 <sup>-6</sup> / year Max.	Ta = +25 °C, first year	
Shock resistance	S.R.	±10 x 10 <sup>-6</sup> Max.	±2 x 10 <sup>-6</sup> Max.	Three drops on a hard board from 750 mm or excitation test with 29400 m/s <sup>2</sup> x 0.3 ms x 1/2sine wave in 3 directions	

## External dimensions

(Unit: mm)



## Recommended soldering pattern

(Unit: mm)

